

25W SURFACE MOUNT TVS BI-DIRECTIONAL FOR ESD PROTECTION-3.3V

DESCRIPTION:



The **ALPLL03BT1006** is 25W Surface Mount TVS Bi-Directional For ESD Protection-3.3V are optimized for high-speed lines, Ideal for Protects one data, control or power line.

FEATURES:

- Package optimized for high-speed lines.
- Ultra-small package (1.0mm x 0.6mm x 0.55mm).
- Protects one data, control, or power line.
- Low capacitance: 0.15pF (Typical).
- Low leakage current: 0.1μA @V_{RWM} (Typical).
- Low clamping voltage.
- Provide transient protection:
 - IEC 61000-4-2 (ESD) ±17KV(Air), ±10KV(Contact).
 - IEC 61000-4-4 (EFT) 40A (5/50ns) Cable discharge event (CDE).
- Each I/O pin can withstand over 1000 ESD Strikes for ±8KV contact discharge.
- We declare that the material of product compliance with RoHS requirements.
- Suffix "-H" indicates Halogen free parts, ex. ALPLL03BT1006-H

APPLICATIONS:

- Serial ATA.
- PCI Express.
- ➤ USB 2.0/3.0/3.1 Power and data line protection.
- ➤ HDMI 1.4/2.0.

MECHANICAL CHARACTERISTICS

> Epoxy: UL94-V0 rated flame retardant.

Package: T1006P2RoHS Compliant

Approximate Weight: 0.73 grams.

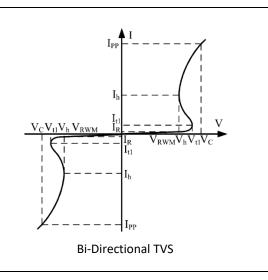


TYPICAL DEVICE CHARACTERISTICS

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	VALUES	UNITS	
Peak pulse power (tp=8/20μs)	P _{PP}	25	Watts	
Peak pulse current (tp=8/20μs)	Ірр	5	Amps	
ESD per IEC 61000-4-2 (Contact)		±10	KV	
ESD per IEC 61000-4-2 (Air)	V _{ESD}	±17		
Operating temperature	Торт	+125	°C	
Storage temperature range	Тѕтс	-55 to +150	°C	

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS	SYMBOL	Min.	Тур.	Max.	UNIT
Reverse stand-off voltage		V_{RWM}			3.3	V
Reverse leakage current	V _{RWM} =3.3V	I _R		0.1	0.5	μΑ
Trigger voltage	I _{t1} =10μΑ	V _{t1}	6.5		8.5	V
Holding voltage	I _h =30mA	V _h		2.4		V
Clamping voltage @IPP	I _{PP} =1A, t _p =8/20μs	Vc			4.0	.,
	I _{PP} =5A, t _p =8/20μs				5.0	V
Junction capacitance	V _R =0V, f=1MHz	Cd		0.15	0.19	pF

PARAMETER	SYMBOL
Nominal Reverse Working Voltage	V_{RWM}
Reverse Leakage Current @ V _{RWM}	I _R
Trigger Voltage	V _{t1}
Trigger Current @ V _{t1}	l _{t1}
Holding Voltage	V _h
Holding Current @ V _h	lh
Clamping Voltage @ IPP	Vc
Maximum Peak Pulse Current	Ірр
Diode Capacitance	Cd



TYPICAL DEVICE CHARACTERISTICS CURVES

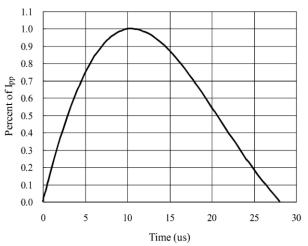


Fig1. 8/20µs PULSE WAVEFORM

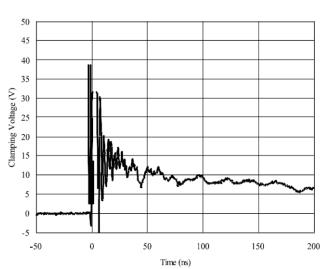


Fig3. ESD CLAMPING of I/O to GND (+8kV Contact per IEC 61400-4-2)

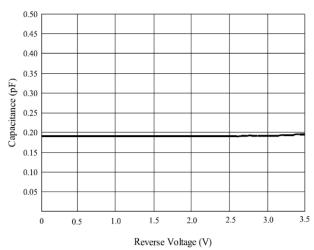


Fig2. CAPACITANCE Vs REVERSE VOLTAGE

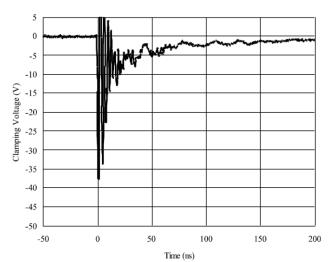
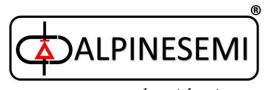
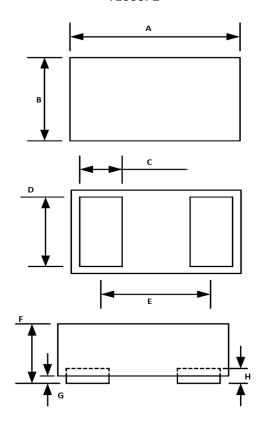


Fig4. ESD CLAMPING of I/O to GND (-8kV Contact per IEC 61400-4-2)



PACKAGE INFORMATION

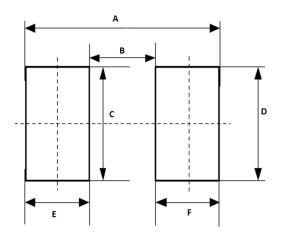
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OUTLINE DIMENSIONS						
DIM	MILLIMET	MILLIMETERS		INCHES		
Dilvi	MIN	MAX	MIN	MAX		
Α	0.95	1.05	0.037	0.041		
В	0.55	0.65	0.022	0.026		
С	0.20	0.30	0.008	0.012		
D	0.45	0.55	0.018	0.022		
Е	0.65 BSC.		0.026 BSC.			
F	0.40	0.55	0.016	0.022		
G	0.00	0.05	0.00	0.002		
Н	0.125 REF.		0.005 REF.			
NOTES						

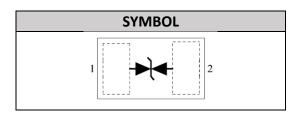
NOTES

1. Dimensions are exclusive of mold flash and metal burrs.



PAD LAYOUT DIMENSIONS			
DIM	MILLIMETERS		
	Тур.		
Α	1.00		
В	0.30		
С	0.60		
D	0.60		
Е	0.35		
F	0.35		

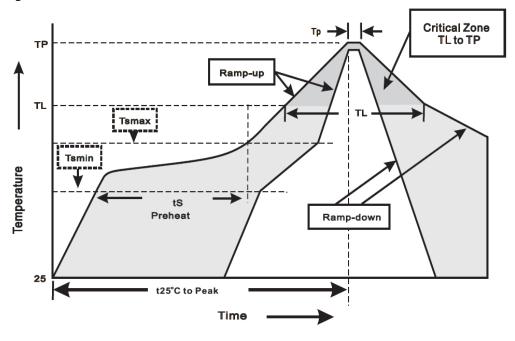
PINNING INFORMATION



SOLDERING PARAMETERS

SUGGESTED THERMAL PROFILES FOR SOLDERING PROCESSES

- 1. Storage environment: Temperature=5 °C~40 °C Humidity=55% ±25%
- 2. Reflow soldering of surface-mount devices



3. Reflow soldering

PROFILE FEATURE	SOLDERING CONDITION
Average ramp-up rate (T _L to T _P)	<3 °C/sec
Preheat	
- Temperature Min (T _{smin})	150 °C
- Temperature Max (T _{smax})	200 °C
- Time (min to max) (t₅)	60 ~ 120 sec
T _{smax} to T _L	
- Ramp-upRate	<3 °C/sec
Time maintained above:	
- Temperature (T∟)	217 °C
- Time(tL)	60 ~ 260 sec
Peak Temperature (T _P)	255 °C-0/+5 °C
Time within 5 °C of actual Peak Temperature(tP)	10 ~ 30 sec
Ramp-down Rate	<6 °C/sec
Time 25 °C to Peak Temperature	<6 minutes

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CUSTOMER NOTE:

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- 1. ALPINESEMI™ Semiconductor Devices are RoHS compliant and hence customers are requested to dispose as per the prevailing Environmental Legislation put forth in their specific country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).



sales@alpinesemi.com www.alpinesemi.com